## Low Noise, Wideband, Low Current

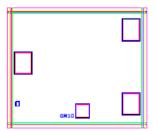
# **Monolithic Amplifier Die**

# PMA2-183LN-D+

 $50\Omega$  4 to 18 GHz

# **The Big Deal**

- Ultra wideband, 4 to 18 GHz
- Excellent noise figure, 2.5 dB at 15 GHz
- Low Current, 48mA typ.
- Usable to 20 GHz



## **Product Overview**

The PMA2-183LN-D+ is a E-PHEMT based wideband, low noise MMIC amplifier die with a unique combination of low noise, high IP3, and low current making it ideal for sensitive, high-dynamic-range receiver applications. This design operates on a single 5V supply, is well matched for  $50\Omega$ .

**Key Features** 

Feature	Advantages		
Excellent Noise Figure up to 18 GHz • 2.7 dB typ. at 4 GHz • 2.5 dB typ. at 18 GHz	Enables lower system noise figure performance.		
High IP3  • +31 dBm at 4 GHz  • +29.2 dBm at 20 GHz	Combination of low noise figure and high IP3 makes this MMIC amplifier ideal for use in low noise receiver front end (RFE) as it gives the user advantages of sensitivity and two-tone IM performance at both ends of the dynamic range.		
Low operating voltage & current 5V & 48mA	Low voltage & current consumption is ideal for use in amplifier chain.		
Unpackaged die	Enables user to integrate it directly into hybrids.		

## Low Noise, Wideband, Low Current

# **Monolithic Amplifier Die**

## PMA2-183LN-D+

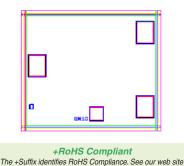
#### $50\Omega$ 4 to 18 GHz

#### **Product Features**

- Ultra wideband, 4 to 18 GHz
- Excellent Noise figure, 2.5 dB at 15 GHz
- Low current, 48mA typ.
- Usable to 20 GHz

#### **Typical Applications**

- WiFi
- WLAN
- LTE
- WiMAX
- C-band Satcom



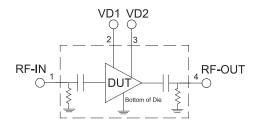
Ordering Information: Refer to Last Page

for RoHS Compliance methodologies and qualifications

## **General Description**

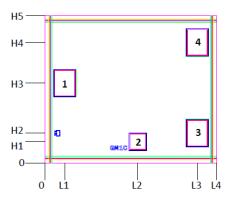
The PMA2-183LN-D+ is a E-PHEMT based wideband, low noise MMIC amplifier die with a unique combination of low noise, high IP3, and low current making it ideal for sensitive, high-dynamic-range receiver applications. This design operates on a single 5V supply, is well matched for  $50\Omega$ .

## Simplified Schematic and Pad description



Pad#	Function			
1	RF-IN			
2	VD1, Connect to VDD			
3	VD2, Connect to VDD			
4	RF-OUT			

## **Bonding Pad Position**



	Dimensions in pini, Typicai												
L1	L2	L3	L4	H1	H2	НЗ	H4	H5	Thickness	Die size	Pad size 1,3&4	Pad size 2	
39	420	689	778	97	136	362	547	668	100	778 x 668	89 x 114	69 x 69	

Dimensions in um Typical

## Electrical Specifications<sup>1</sup> at 25°C, Zo=50 $\Omega$ unless noted

Parameter	Condition (GHz)		V <sub>DD</sub> =5.0V		
		Min.	Тур.	Max.	
requency Range		4		18	GHz
Gain	4		13.2		dB
	10		11.8		
	12		10.4		
	15		10.9		
	18		10.2		
	20		9.3		
nput Return Loss	4		10		dB
	10		11		
	12		11		
	15		15		
	18		12		
	20		11		
Output Return Loss	4		12		dB
	10		15		
	12		15		
	15		20		
	18		13		
	20		11		
Output Power at 1dB Compression	4		16		dBm
·	10		14.4		
	12		14.2		
	15		15.8		
	18		14.6		
	20		12.8		
Output IP3	4		31		dBm
	10		26.3		
	12		25.6		
	15		28.1		
	18		27.7		
	20		29.2		
loise Figure	4		2.7		
·	10		2.5		
	12		2.5		
	15		2.5		
	18		2.5		
	20		2.9		
Device Operating Voltage (V <sub>DD</sub> )		4.75	5	5.25	V
Device Operating Current (I <sub>DD</sub> )		_	48.2	58	mA
Device Current Variation vs. Temperature <sup>2</sup>			2.31		μΑ/°C
Device Current Variation vs. Voltage <sup>3</sup>			0.01		mA/mV
Thermal Resistance, junction-to-ground lead			71.9		°C/W

<sup>1.</sup> Measured on Mini-Circuits Characterization Test Board TB-PMA2-183LN+. Die is packaged in 2X2 mm, 8-lead MCL package and soldered on TB-PMA2-183LN+. See Characterization Test Circuit (Fig. 1)

## **Absolute Maximum Ratings<sup>4</sup>**

Parameter	Ratings	
Operating Temperature (ground lead)	-40°C to 85°C	
Junction Temperature	141°C	
Total Power Dissipation	0.95W	
Input Power (CW), V <sub>DD</sub> =5V	+24 dBm (5 minutes max.) +12 dBm (continuous)	
DC Voltage	7V	

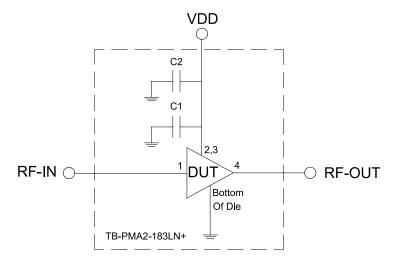
Permanent damage may occur if any of these limits are exceeded.

Electrical maximum ratings are not intended for continuous normal operation.



<sup>2.</sup> Device Current Variation vs. Temperature= (Current at 85°C - Current at -45°C)/130 3. Device Current Variation vs. Voltage = (Current at 5.25V - Current at 4.75V) / ((5.25V-4.75V)\*1000 mV/V)

## **Characterization Test Circuit**



Component	Size	Value	Part Number	Manufacturer
C1	0402	100pF	GRM1555C1H101JA01J	Murata
C2	0402	0.1uF	GRM155R71C104KA88D	Murata

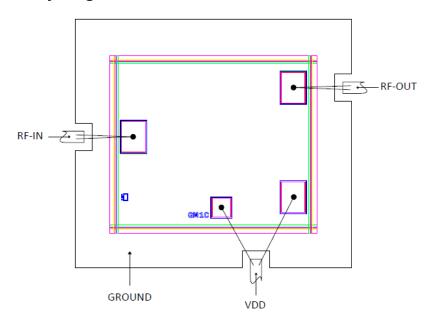
Fig 1. Application and Characterization Circuit

Note: This block diagram is used for characterization. (Die is packaged in 2X2 mm, 8-lead MCL package and soldered on TB-PMA2-183LN+.) Gain, Return loss, Output power at 1dB compression (P1dB), output IP3 (OIP3) and noise figure measured using Agilent's N5242A PNA-X microwave network analyzer.

#### Conditions

- 1. Gain and Return loss: Pin= -25dBm
- 2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 0 dBm/tone at output.

#### **Assembly Diagram**



## **Assembly and Handling Procedure**

- 1. Storage
  - Dice should be stored in a dry nitrogen purged desiccators or equivalent.
- 2. ESD

MMIC E-PHEMT amplifier dice are susceptible to electrostatic and mechanical damage. Dice are supplied in antistatic protected material, which should be opened in clean room conditions at an appropriately grounded anti-static worksta tion. Devices need careful handling using correctly designed collets, vacuum pickup tips or sharp antistatic tweezers to deter ESD damage to dice.

- 3. Die Attach
  - The die mounting surface must be clean and flat. Using conductive silver filled epoxy, recommended epoxies are DieMat DM6030HK-PT/H579 or Ablestik 84-1LMISR4. Apply sufficient epoxy to meet required epoxy bond line thickness, epoxy fillet height and epoxy coverage around total die periphery. Parts shall be cured in a nitrogen filled atmosphere per manufacturer's cure condition. It is recommended to use antistatic die pick up tools only.
- 4. Wire Bonding
  - Bond pad openings in the surface passivation above the bond pads are provided to allow wire bonding to the dice gold bond pads. Thermosonic bonding is used with minimized ultrasonic content. Bond force, time, ultrasonic power and temperature are all critical parameters. Suggested wire is pure gold, 1 mil diameter. Bonds must be made from the bond pads on the die to the package or substrate. All bond wires should be kept as short as low as reasonable to minimize performance degradation due to undesirable series inductance.

Additional Detailed Technic additional information is available on ou						
	Data Table					
Performance Data	Swept Graphs	Swept Graphs				
	S-Parameter (S2P Files) Data Set with	S-Parameter (S2P Files) Data Set with and without port extension(.zip file)				
Case Style	Die	Die				
	Quantity, Package	Model No.				
	Small, Gel - Pak: 5,10,50,100 KGD*					
Die Ordering and packaging information	Medium <sup>†</sup> , Partial wafer: KGD*<2112 Large <sup>†</sup> , Full Wafer	PMA2-183LN-DP+ PMA2-183LN-DF+				
information	†Available upon request contact sales representative					
	Refer to <u>AN-60-067</u>					
Environmental Ratings	ENV80					

<sup>\*</sup>Known Good Dice ("KGD") means that the dice in question have been subjected to Mini-Circuits DC test performance criteria and measurement instructions and that the parametric data of such dice fall within a predefined range. While DC testing is not definitive, it does help to provide a higher degree of confidence that dice are capable of meeting typical RF electrical parameters specified by Mini-Circuits.

## **ESD Rating\*\***

Human Body Model (HBM): Class 1A (250 to <500V) in accordance with ANSI/ESD STM 5.1 - 2001

#### **Additional Notes**

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/MCLStore/terms.jsp
- D. Mini-Circuits does not warrant the accuracy or completeness of the information, text, graphics and other items contained within this document and same are provided as an accommodation and on an "As is" basis, with all faults.
- E. Purchasers of this part are solely responsible for proper storing, handling, assembly and processing of Known Good Dice (including, without limitation, proper ESD preventative measures, die preparation, die attach, wire bond ing and related assembly and test activities), and Mini-Circuits assumes no responsibility therefor or for environmental effects on Known Good Dice.
- F. Mini-Circuits and the Mini-Circuits logo are registered trademarks of Scientific Components Corporation d/b/a Mini-Circuits. All other third-party trademarks are the property of their respective owners. A reference to any third-party trademark does not constitute or imply any endorsement, affiliation, sponsorship, or recommendation by any such third-party of Mini-Circuits or its products.



<sup>\*\*</sup> Tested in industry standard MCLP 2x2 mm, 8-lead package.







All Mini-Circuits products are manufactured under exacting quality assurance and control standards, and are capable of meeting published specifications after being subjected to any or all of the following physical and environmental test.

Specification	Test/Inspection Condition	Reference/Spec
Operating Temperature	-40° to 85° C or -40° to 105° C or -55° to 105° C or -45° to 105° C 105° C Ambient Environment	Refer to Individual Model Data Sheet
Storage Environment (Die)	-65° to 150°C	Individual Model Data Sheet
Storage Environment(Packaging)	-40° to 70°C and 40 to 60% humidity (In Factory Shipped Package)	

ENV80 Rev: C

06/10/24 DCO-1455 File: ENV80.pdf

This document and its contents are the property of Mini-Circuits.